

SAM™ Data Sheet SAM-1064-33-30ps-x, $\lambda = 1064 \text{ nm}$

Laser wavelength	$\lambda = 1064 \text{ nm}$
High reflectance region	$\lambda = 1010 \text{ nm} \dots 1120 \text{ nm}$
Absorbance	$A_0 = 33 \%$
Modulation depth	$\Delta R = 20 \%$
Non-saturable loss	$A_{ns} = 13 \%$
Saturation fluence	$\Phi_{sat} = 50 \mu\text{J}/\text{cm}^2$
Relaxation time constant	$\tau \sim 30 \text{ ps}$
Damage threshold	$\Phi = 2 \text{ mJ}/\text{cm}^2$
Chip area	4.0 mm x 4.0 mm; other dimensions on request
Chip thickness	450 μm
Protection	the SAM is protected with a dielectric front layer
Mounting option x denotes the type of mounting as follows:	
x = 0	unmounted
x = 12.7 g	glued on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 g	glued on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = 12.7 s	soldered on a gold plated Cu-cylinder with 12.7 mm \varnothing
x = 25.4 s	soldered on a gold plated Cu-cylinder with 25.4 mm \varnothing
x = FC	mounted on a 1 m monomode fiber cable with FC connector

Low intensity spectral reflectance

